

Coexistence of Superconductivity and Charge Density Waves in Tantalum Disulfide: Experiment and Theory

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The coexistence of charge density wave (CDW) and superconductivity in tantalum disulfide (2H-TaS₂) at low temperature is boosted by applying hydrostatic pressures to study both vibrational and magnetic transport properties. Around P_c , we observe a superconducting dome with a maximum superconducting transition temperature $T_c = 9.1$ K. First-principles calculations of the electronic structure predict that, under ambient conditions, the undistorted structure is characterized by a phonon instability at finite momentum close to the experimental CDW wave vector. Upon compression, this instability is found to disappear, indicating the suppression of CDW order. The calculations reveal an electronic topological transition (ETT), which occurs before the suppression of the phonon instability, suggesting that the ETT alone is not directly causing the structural change in the system. The temperature dependence of the first vortex penetration field has been experimentally obtained by two independent methods. While a d wave and single-gap BCS prediction cannot describe the lower critical field H_{c1} data, the temperature dependence of the H_{c1} can be well described by a single-gap anisotropic s -wave order parameter.

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Coexistence of superconductivity with competing physical phenomena such as magnetic or charge order has been of interest for the condensed matter community for a long time [1–3]. A commonly accepted argument says that for the materials exhibiting competing ground states, suppressing the magnetic or charge order helps to stabilize the superconducting (SC) phase. This is the case, for instance, in layered materials that are composed of two-dimensional (2D) building blocks, with periodic modulations of the charge carrier density, so-called charge density waves (CDWs) [4–6]. Classic examples are the members of the transition-metal dichalcogenide family (TMDs) MX₂, where $M = \text{Nb, Ti, Ta, Mo}$ and $X = \text{S, Se}$. TMDs provide an ideal playground for studying semiconductors, metals, and superconductors in 2D using the same structural template [7–10]. At ambient pressure and without intercalation or chemical

substitution, 2H-TaS₂, a prominent member of the vast family of TMDs, exhibits both superconductivity and a canonical CDW phase transition whose mechanisms remain controversial, even after decades of research [11–13]. Despite extensive studies, the current understanding of the microscopic origin of the SC mechanism and the CDW state is not complete. The SC transition temperature (T_c) increases while the CDW lock-in temperature falls down with chemical doping [13], increasing thickness of the sample [14], and external pressure [15–17]. Several theoretical mechanisms behind the formation of CDW have been proposed [18]. For TMDs, the following origins were extensively discussed: Fermi surface nesting [19], saddle points near Fermi surface [20], exciton-phonon [21], or electron-phonon coupling [22–26]. The most recent experimental evidence suggests that the latter plays a decisive role for CDW stabilization in Ta systems [27,28]. It is thus of profound importance to understand the interplay between electronic and crystal structure in 2H-TaS₂. Additionally, there is no general consensus on the origin of SC pairing mechanisms in this material and further studies are necessary to elucidate this issue.

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Whatever the proposed understanding of the relation between CDW and superconductivity is, it is important to determine the exact dependence of T_c and the CDW phase with pressure [11]. Within this scope, through combined complementary experimental techniques supplemented with theoretical calculations on 2H-TaS₂ [29], we derive a previously not discussed pressure-temperature phase diagram. We explore external pressure as a tool to tune the phonon dispersions and thus the stability of the CDW phase. Pressure is considered a very clean way to tune basic electronic and structural properties without changing the stoichiometry of a material [30,31]. Our analysis shows that the temperature dependence of the lower critical fields, $H_{c1}(T)$, is inconsistent with a simple isotropic *s*-wave type of the order parameter but are rather in favor of the presence of an anisotropic *s* wave. These observations clearly show that the SC energy gap in 2H-TaS₂ is nodeless.

Raman response of 2H-TaS₂ at ambient pressure and room temperature is presented in Fig. 1(a), where three regular phonons are observed: (i) Two-phonon process at 180.3 cm⁻¹; (ii) E_{2g} , an in-plane vibrational mode at 288.1 cm⁻¹; and (iii) A_{1g} the out-of-plane mode at 405.4 cm⁻¹. These values agree well with the reported works [32,33]. Figure 1(b) shows the Raman spectra under hydrostatic pressure up to 40 GPa. The two-phonon mode originates from second order scattering of acoustic and quasiaoustic momentum phonons near the CDW wave vector. By application of pressure, all Raman modes show decreases in intensity, the peaks become wider, and the positions show blueshifts. Moreover, we observed a splitting of E_{2g} peak at 20.2 GPa which may be due to the pressure-induced structural phase transition in 2H-TaS₂. The positions of the three peaks vs pressure are shown in Fig. 1(c). The Raman mode at 180.3 cm⁻¹, which

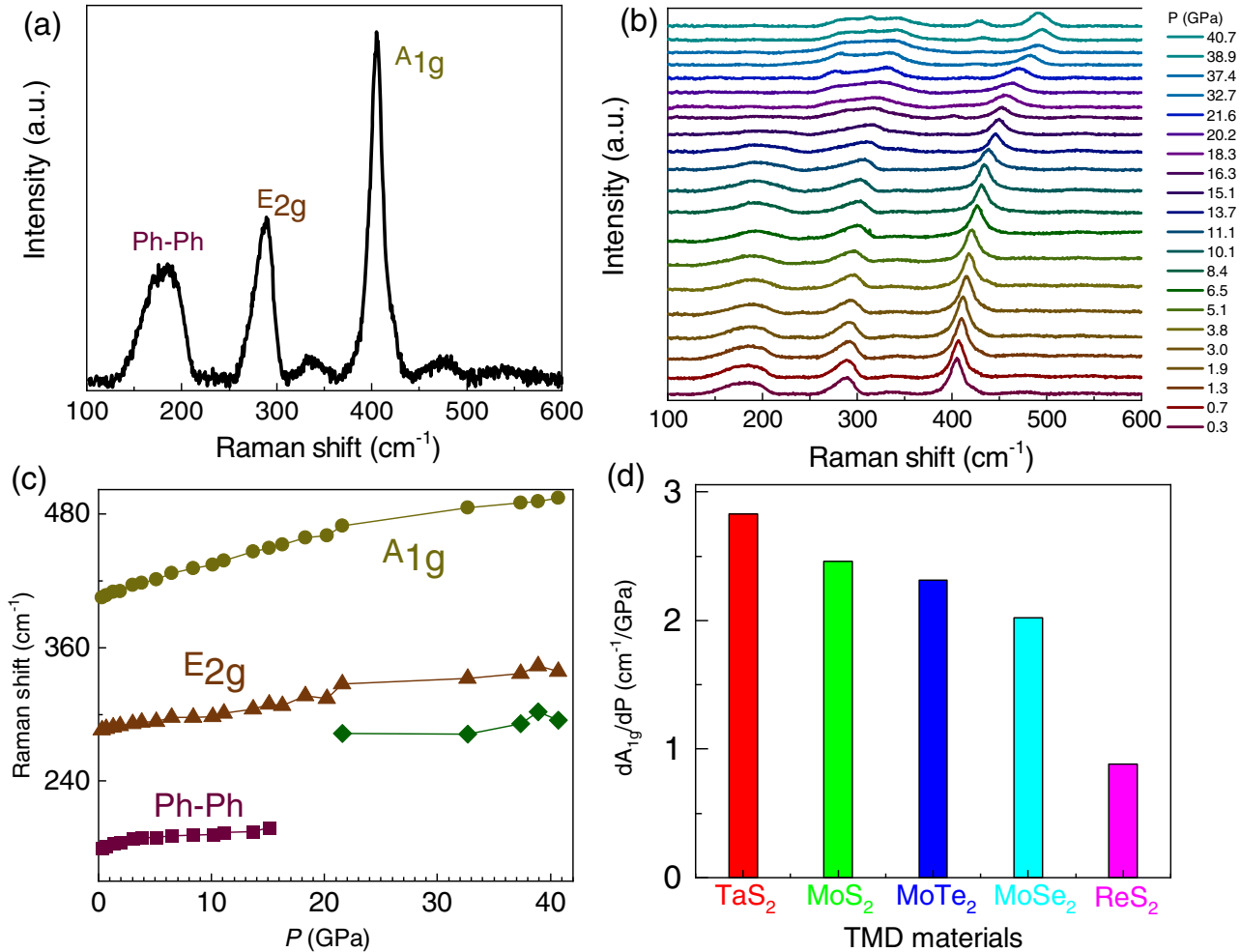


FIG. 1. (a) Raman scattering spectra of 2H-TaS₂ under room temperature and ambient pressure. (b) Raman spectra under various hydrostatic pressures up to 40 GPa at room temperature. (c) Pressure dependence of various vibrational modes in 2H-TaS₂. Ph-Ph refers to a two-phonon mode. (d) Comparison of the pressure coefficient (dA_{1g}/dP) of the out-of-plane (A_{1g}) Raman peaks of TaS₂, MoS₂, MoTe₂, MoSe₂, and ReS₂ [35]. One can see that the out-of-plane mode of TaS₂ presents the highest pressure coefficient among all selected materials.

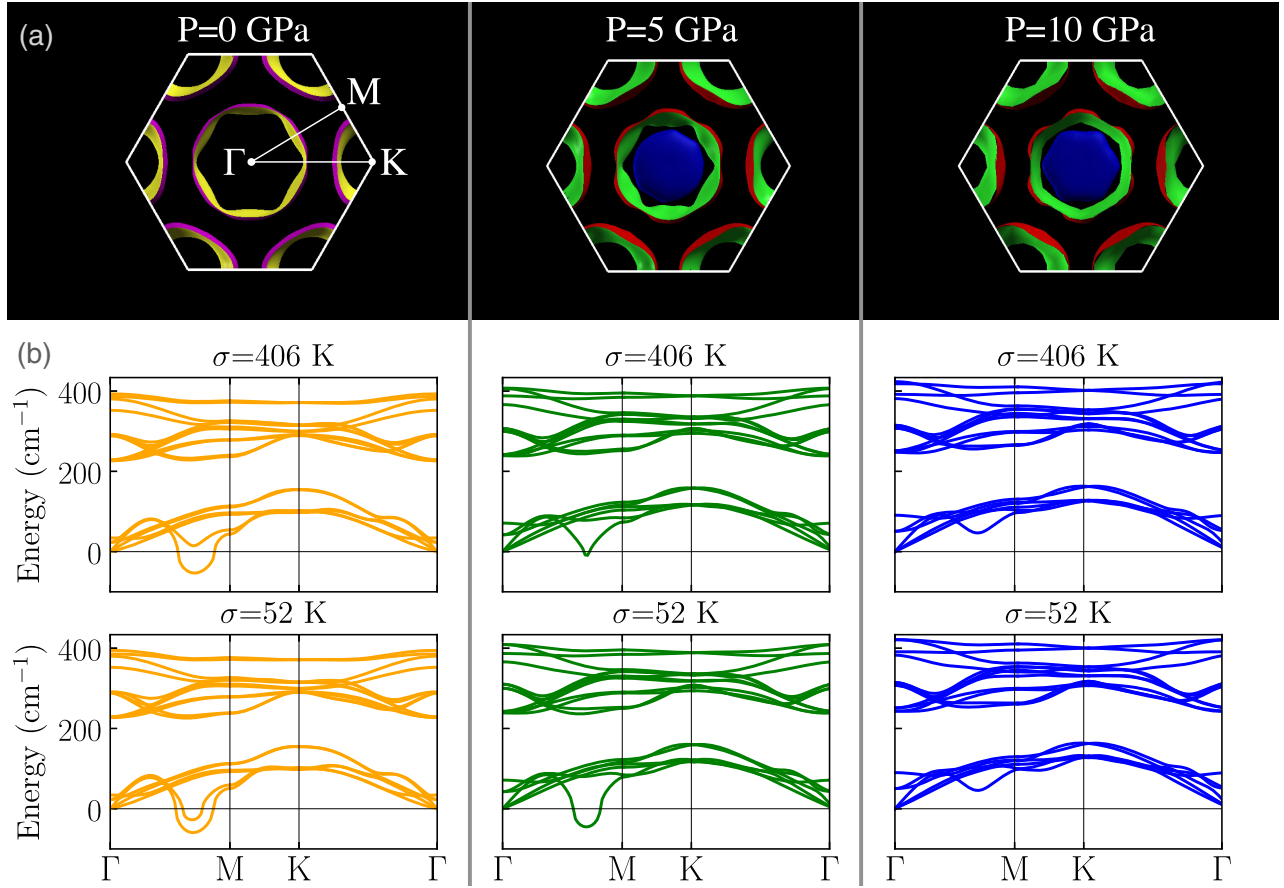


FIG. 2. Calculated Fermi surfaces (a) and phonon dispersions (b) for three different values of external pressure. The phonon dispersions were calculated for two different electronic temperatures, defined by the smearing parameter σ . The Fermi surface was plotted using XCrySDen software (see text for more details).

represents a two-phonon mode, is detectable up to 15.1 GPa, whereas other peaks exist up to our final pressure of 40 GPa. The temperature dependency of the two-phonon mode is similar at ambient and high pressure, and suppression of the two-phonon mode by reduction of temperature results in the appearance of the CDW mode [34]. So, a pressure-induced structural phase transition could be expected well above critical pressure of the two-phonon mode of 15.1 GPa. For the case of the A_{1g} mode, it shows a blueshift with a deformation coefficient of $2.83 \text{ cm}^{-1}/\text{GPa}$. Pressure coefficients of A_{1g} modes of similar TMDs are compared in a bar diagram [Fig. 1(d)]. As the A_{1g} mode is vibrationally coupled with the E_{2g} mode in the case of TaS_2 , the pressure coefficient of the A_{1g} mode of 2H-TaS₂ is higher than in any other TMD material. As the pressure increases, the pressure coefficient of A_{1g} is reduced above 20 GPa, at which bifurcation of the E_{2g} mode starts to occur. As noticed in MoS_2 [35], this phenomenon might be due to the structural transition.

Recently, first-principles calculations have shown that the electron-phonon interactions depend on both the amount of applied strain and the direction in 2H-TaSe₂ [36]. In addition, a sudden change in the E_{2g} mode in

2H-TaSe₂ is observed [28]. In order to get a physical insight into the suppression of the CDW phase under pressure, we have investigated the electronic structure by means of *ab initio* theory. The main results are shown in Fig. 2. According to the results obtained for undistorted 2H-TaS₂, the material undergoes a pressure-induced electronic topological (so-called Lifshitz [37]) transition. An additional hole pocket around the Γ point emerges, as shown in blue on Fig. 2(a). This transition happens below 2.5 GPa, and upon further compression, at least up to 15 GPa, the Fermi surface topology is intact, while its shape becomes slightly modified. The pressure evolution of the calculated phonon spectra is shown in Fig. 2(b). At the equilibrium, and under small applied pressures, there is a phonon instability along the Γ - M direction at the wave vector close to experimental q_{CDW} . Upon compression, the instability is suppressed somewhere between 5 and 10 GPa, indicating the suppression of the CDW order. Interestingly, the instability disappears after the ETT, which indicates that the Fermi surface nesting itself is not the only driving force of CDW order, which is in line with other, more recent studies on 2H-TaS₂ [27]. The results of our calculations for ambient pressure are in agreement with Ref. [33]. These

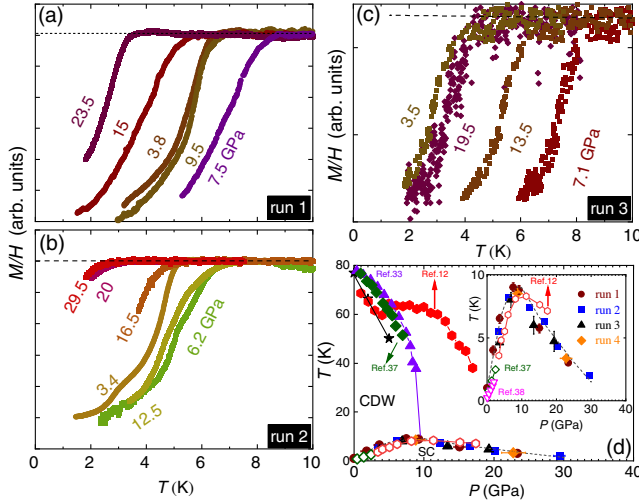


FIG. 3. (a)–(c) The temperature dependence of the dc susceptibility components of 2H-TaS₂ measured in dc field with an amplitude of 30 Oe at elevated pressures in three runs. (d) The obtained pressure-temperature (P - T) phase diagram of 2H-TaS₂. Pressure dependence of the SC transition temperatures T_c up to 30 GPa. The values of T_c were determined from the high-pressure resistivity and dc magnetic susceptibility [11,29]. The temperature dependence on the disappearance of the CDW as a function of pressure, is shown as stars and the data points from the work of Refs. [12,32,39,40] were taken for comparison.

types of calculations are not able to properly capture the CDW transition temperature, but show a correct qualitative behavior. As the electronic temperature increases, the phonon instability becomes less pronounced, but persists up the temperatures well above experimental CDW ordering temperature. The authors of Ref. [33] attribute this to the presence of a short-range CDW state. We would like to note, however, that the employed treatment of the temperature effects is potentially oversimplified and does not capture many phenomena. The main reason is an incomplete description of the electronic correlations within DFT. Moreover, certain crystal structures are known to be stabilized due to anharmonic effects [38]. An explicit account of the electron-phonon interaction which is expected to be quite anisotropic [27] might induce strong modifications of both electronic and phononic spectra.

High-pressure magnetic measurements have repeated in four independent runs using different pieces of the same sample and the data are highly reproducible, Figs. 3(a)–3(c) [38]. The domelike evolution of T_c was constructed based on the observed pressure-dependent magnetization data shown in Fig. 3(d). The data points from Refs. [12,32,39,40] were taken for comparison. Some notable differences with Ref. [12] can be seen. This discrepancy might result from the presence of a pseudogap as reported by ARPES measurements at ambient pressure above T_{CDW} and which may survive up to higher temperatures [41]. As displayed in Figs. 3(a)–3(c), it is clear that T_c

increased up to a pressure of 8.5 GPa, where it exhibits a maximum, then immediately begins to turn down. This kind of dome-shaped curve is one of the hallmarks of high temperature superconductors, but many mysteries around these types of domes remain to be explained [42]. Deriving a solid picture of the origin of the SC dome constitutes a major challenge. Applying external pressure to the system simply modifies the interatomic spacing, wave function overlap and electronic structure, as well as the balance between kinetic energy and Coulomb interaction among the electrons. The SC state certainly depends on these parameters, which is determined by both the pressure and the existence of the CDW state. Since both pressure and the CDW state heavily influence T_c , the competition between the two might be the cause of the SC dome.

Low-temperature ac susceptibility, χ' , measurements as illustrated in Fig. 4(a). T_c of 1.2 K has been extracted from the bifurcation point between χ'_v and χ''_v . One can clearly see that the maximum of the imaginary part of ac susceptibility, see Fig. 4(a) (right inset), shifts to higher temperatures upon increasing the frequency which we attribute that to the motion of vortices. The lower critical field is a very useful parameter providing key information regarding bulk thermodynamic properties. The most popular approach of determining the H_{c1} compared with the values obtained from the onset of the trapped magnetic moment [M_t , Fig. 4(c)] [29]. We have confirmed the absence of the surface barriers in our case from the very symmetric dc magnetization hysteresis curves at 350 mK [Fig. 4(a) (left inset)]. The experimental values of H_{c1} were corrected by accounting for the demagnetization effects and the absolute value can be estimated by using the relation proposed by Brandt [43]. The most intriguing feature in Fig. 4(d) is the upward trend with negative curvature over the entire temperature range, similar features are reported in Refs. [44,45]. The obtained experimental temperature dependence of H_{c1} shown in Fig. 4(d) was analyzed using the phenomenological α model [29,46]. The main features from the corrected H_{c1} values in Fig. 4(d) can be described in the following way: (i) As a first step we compare our data to the single band s wave and we find a systematic deviation at high temperature data; (ii) more obvious deviations exist in the case of d -wave approach [46]. This clearly indicates that the gap structure of our system is more likely to be nodeless s wave, and (iii) then, the anisotropic s wave is further introduced to fit the experimental data. For the anisotropic s wave, the fitting with the magnitude of the gap $\Delta_0 = 1.21$ meV with an anisotropy parameter ≈ 1.01 . As can be seen the anisotropic s -wave order parameter presents a good description to the data. We hence conclude that in TaS₂ the exotic SC gap structure is related to the Ta tubular sheets and that, even if the charge density wave is perturbing those sheets in TaS₂, this CDW does not affect the SC gap structure.

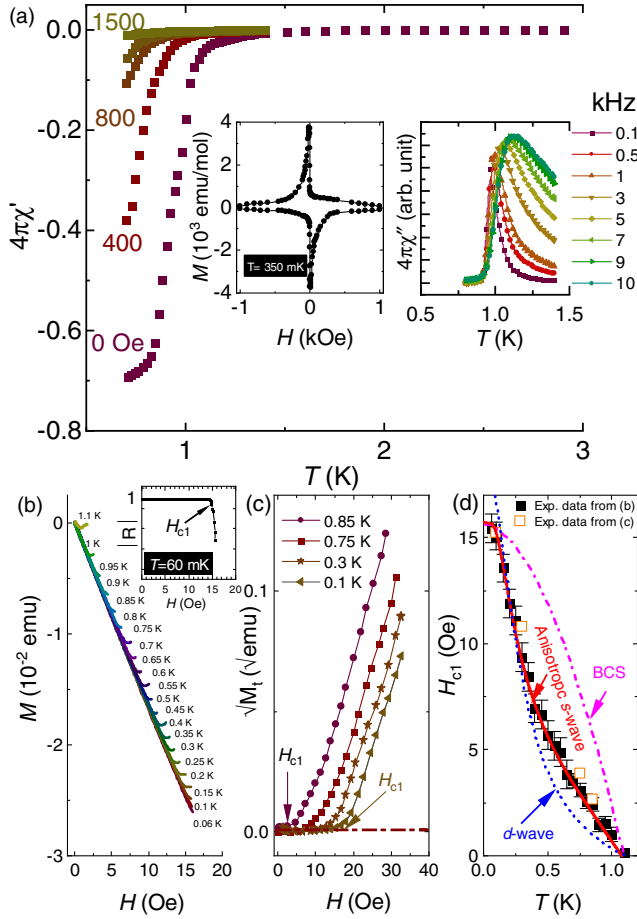


FIG. 4. (a) The temperature dependence of the complex ac susceptibility $4\pi\chi'$ measured in an ac field with an amplitude of 5 Oe and a frequency of 1 kHz. The insets illustrate the magnetization M vs H loops measured at 350 mK and the imaginary part of ac at various frequency (ν_m). (b) The SC initial part of the magnetization curves measured at various temperatures down to 60 mK. The inset depicts an example used to determine the H_{c1} value using the regression factor R , at $T = 60$ mK [29]. (c) The field dependence of $\sqrt{M_t}$ at various temperatures. The arrows indicate H_{c1} values that estimated by extrapolating the linear fit of $\sqrt{M_t}$ to 0. (d) Phase diagram of H_{c1} for the field applied parallel to the c axis. The solid red line is the fitting curves using anisotropic s -wave approach. The dotted and dashed lines represent the d wave and a single-gap BCS approach, respectively.

The temperature-pressure phase diagram of TaS_2 is demonstrated here to have a domelike SC phase with a maximum SC transition temperature $T_c = 9.1$ K. By employing *ab initio* electronic structure theory, we were able to investigate the temperature and pressure dependence of the phonon spectrum. It is shown that, at ambient conditions, there is a phonon instability at the propagation vector close to the q_{CDW} wave vector. Furthermore, the temperature dependence measurements of the critical field are consistent with single gap anisotropic s -wave superconductivity. The role of the two-phonon mode on the

CDW transition, which was highlighted in prior studies [34] needs to be better understood and calls for additional low-temperature Raman measurements.

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